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Supplementary Materials: Incorporation of Mg^{2+}/Si^{4+} in $ZnGa_2O_4:Cr^{3+}$ to Generate Remarkably Improved Near-Infrared Persistent Luminescence

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Table S1. The binding energies of the Zn $2p_{3/2}$ core-levels of ZGMSO:Cr^{3+}.

x	Binding Energy	Area Percent
0	1022.53	23.60
	1021.97	76.40
0.01	1022.34	26.27
	1021.93	73.73
0.15	1022.20	30.14
	1021.76	69.86

Table S2. The binding energies of the Ga $2p_{3/2}$ core-levels of ZGMSO:Cr^{3+}.

x	Binding Energy/eV	Area Percent
0	1118.03	84.38
	1117.47	15.62
0.01	1118.15	83.16
	1117.84	16.84
0.15	1117.96	81.85
	1117.38	18.15

Table S3. The binding energies of the Mg 1s core-levels of ZGMSO:Cr^{3+}.

x	Binding Energy/eV	Area Percent
0.01	1303.99	51.58
	1299.76	48.42
0.15	1304.13	34.34
	1300.71	65.66

Table S4. The binding energies of the Si 2p core-levels of ZGMSO:Cr^{3+}.

x	Binding Energy/eV	Area Percent
0.01	108.95	27.69
	105.20	72.31
0.15	109.01	24.23
	105.20	75.77